

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

IRLR7843, IIRLR7843

FEATURES

- Static drain-source on-resistance: Ros(on)≤3.3mΩ
- Enhancement mode:
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

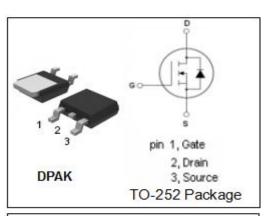
• High Frequency Synchronous Buck Converters For Computer Processor Power

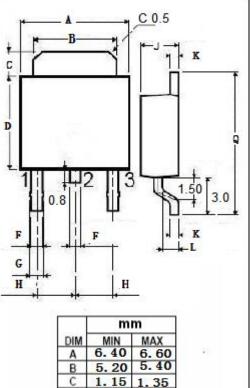
ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT			
V _{DSS}	Drain-Source Voltage	30	V			
V _{GS}	Gate-Source Voltage	±20	V			
ID	Drain Current-Continuous	161	А			
I _{DM}	Drain Current-Single Pulsed	620	А			
PD	Total Dissipation @Tc=25°C 140		W			
Tj	Max. Operating Junction Temperature	175	°C			
T _{stg}	Storage Temperature	-55~175	°C			

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT	
Rth(j-c)	Channel-to-case thermal resistance	1.05	°C/W	
Rth(j-a)	Rth(j-a) Channel-to-ambient thermal resistance		°C /W	





5.70 6. 0.65 0.

2.10

2.10

0.40 0.90 9.90 75

2 50

10

2.40

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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =250 μ A	30			V
V _{GS} (th)	Gate Threshold Voltage	VDS=VGS; I _D =250 µ A	1.4		2.3	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =15A			3.3	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =24V; V _{GS} = 0V			1	μA
V _{SD}	Diode forward voltage	I _s =12A, V _{GS} = 0V			1.0	V

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